



PSB Upgrade
LIU Project

Internal H0/H- dump

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On behalf of EN/STI

Thanks to: A. Christov, C. Maglioni, S. Mathot, C. Pasquino, A. Patapenka



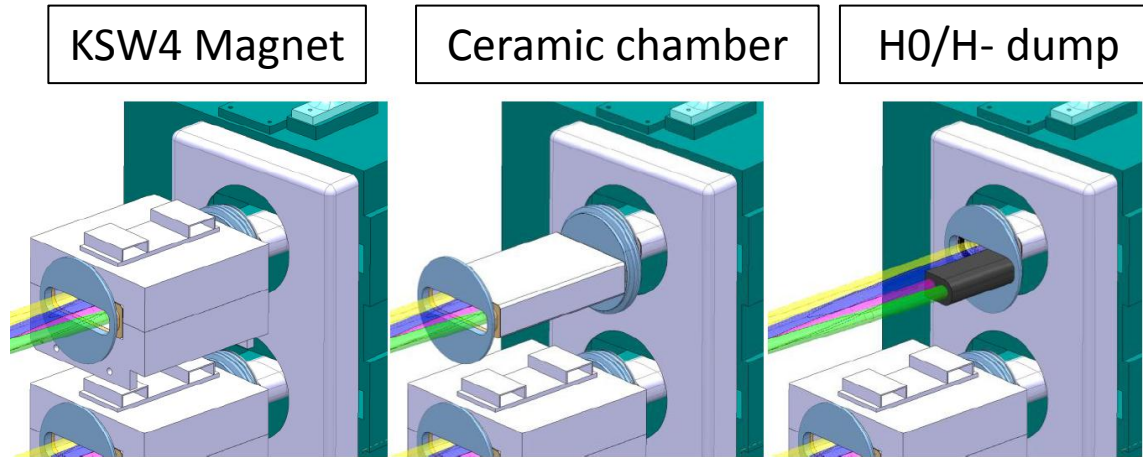
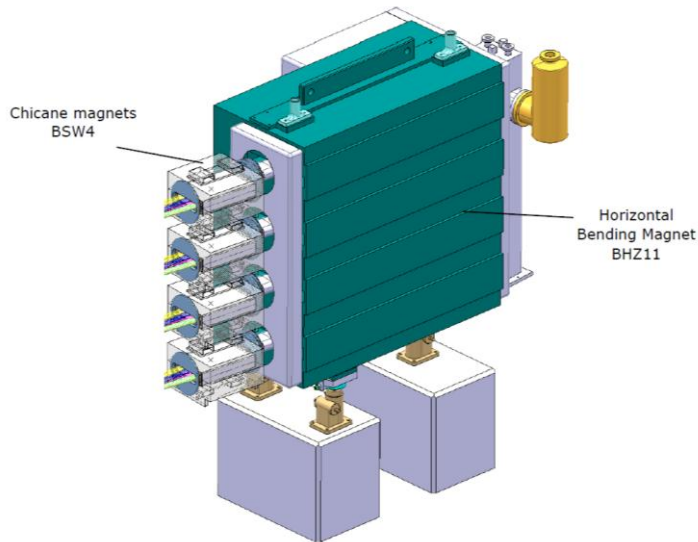
Outline

- Dump space and layout
- Specifications
- Support
- Summary
- Conclusion



Dump space and layout: actual design

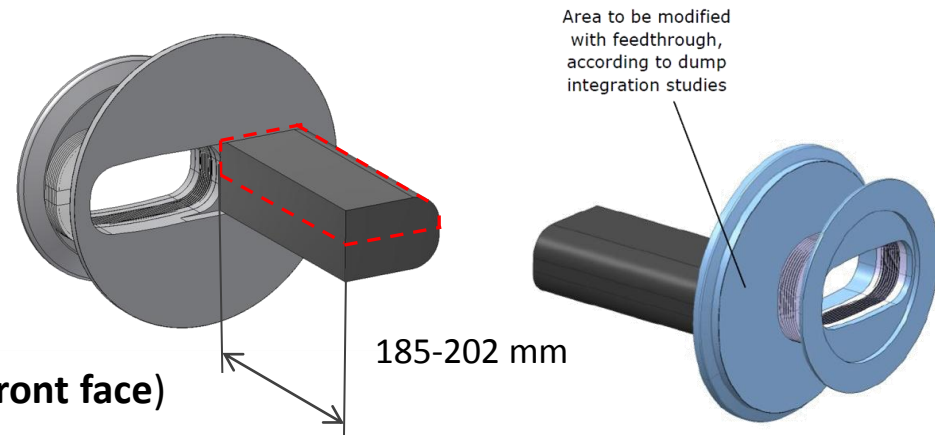
EDMS 1163508



The flange has to be adapted to the assembly / fixation / cooling needs of the dump

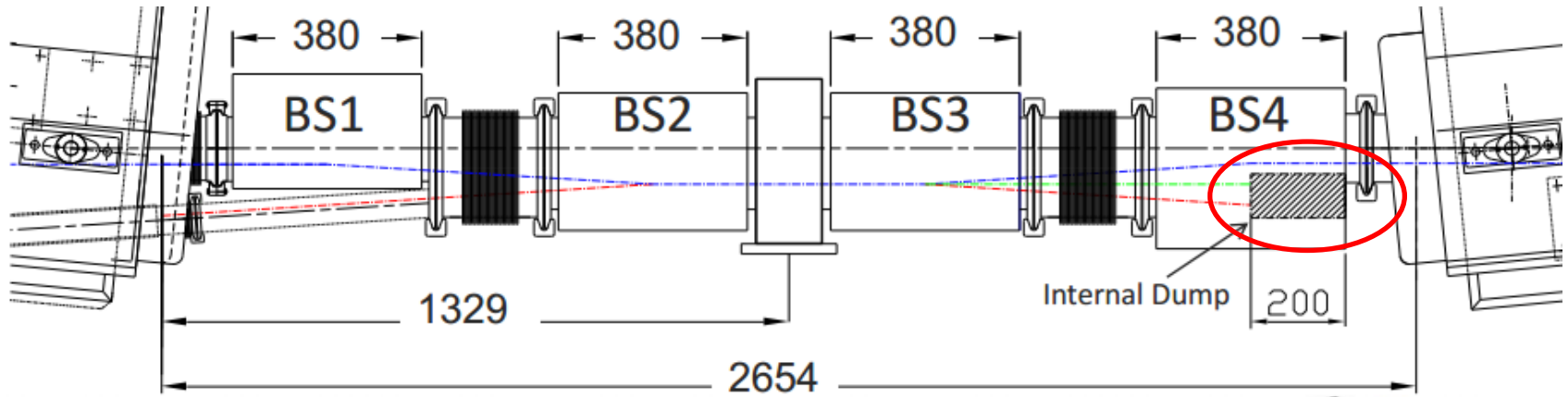
The instrumentation has to be fixed on the dump (**front face**)

The dump is one-piece with the flange (ALARA, quick exchange / disassembly)





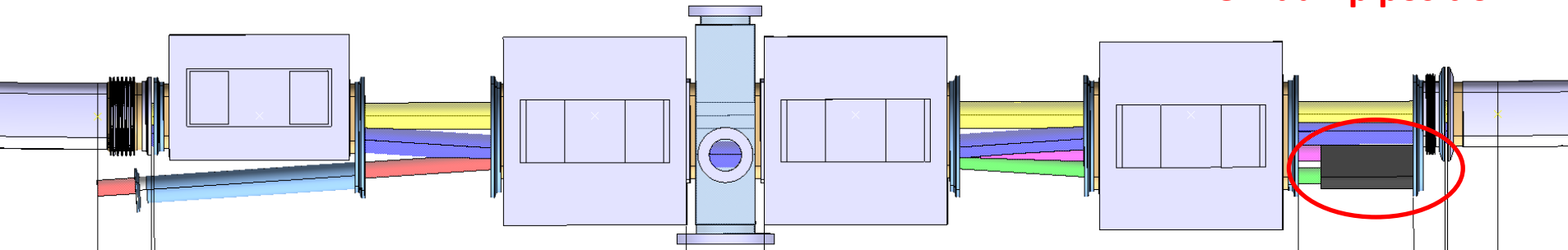
Dump space and layout: shorter dipole



Actual dump position

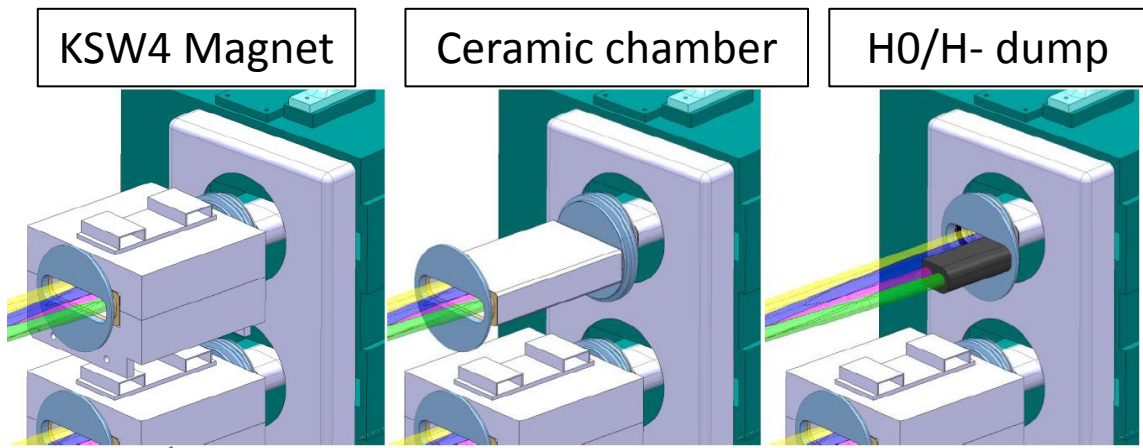


New dump position



Wim Wetering, presentation of 09/12/11 and 20/03/2012

Specifications (EDMS 1069240)



Charged beam

Completely non-magnetic and induce very little eddy current



Ceramic material

The dump must cope with maximum temperature on ceramic chamber (fixed at **100 °C**)



Active cooling required

Risk of electrically charging the dump



Electrical resistivity and capacitance to be reduced as much as possible

Specifications (EDMS 1069240)



Thermo-structural integrity of dump

- Dump must handle the temperature and stresses induced



Vacuum

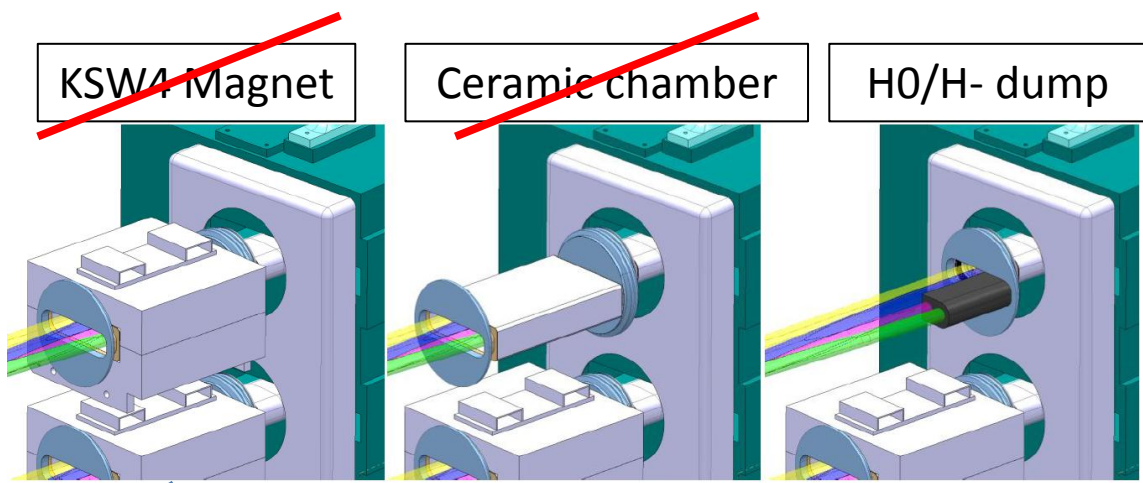
- Reduce as much as possible degassing rate



Activation

- To be reduce as much as possible

Shorter dipole



Completely non-magnetic and induce very little eddy current

Metallic, denser material allowed

The dump must cope with maximum temperature on ceramic chamber (fixed at **100 °C**)

Active cooling may NOT be required

Charged beam
Risk of electrically charging the dump

Electrical resistivity and capacitance to be reduced as much as possible

Shorter dipole



Thermo-structural integrity of dump



- Dump must handle the temperature and stresses induced



Vacuum



- Reduce as much as possible degassing rate

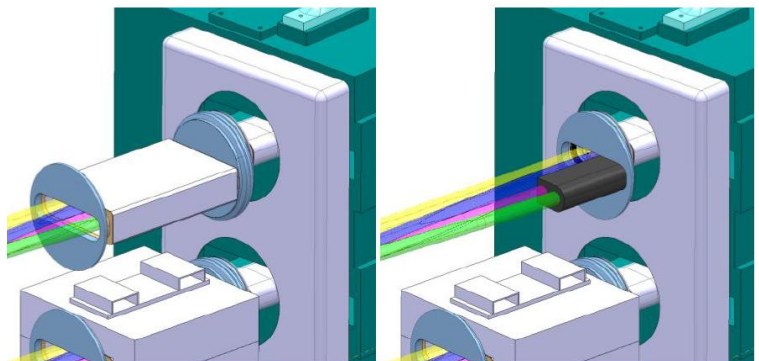


Activation



- To be reduce as much as possible

Envisaged support actual configuration

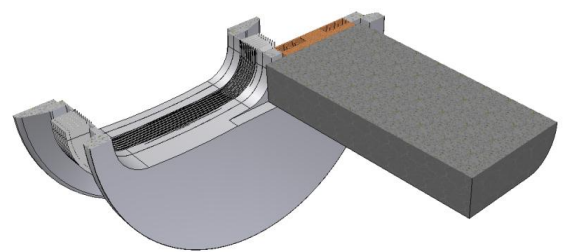


Need to be implemented within the area:

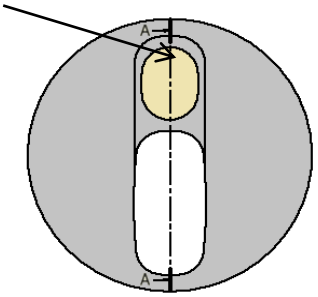
- *beam instrumentation*
- *dump support*
- *active cooling system*

2 possible methods of fixation:

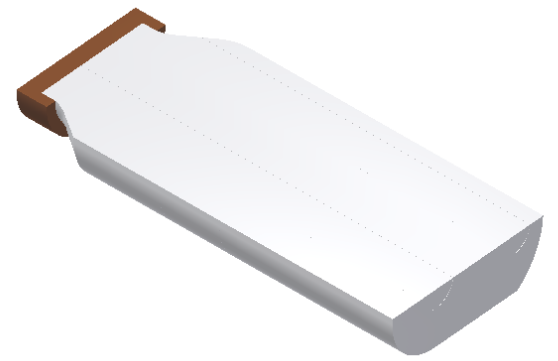
- **Metallization + Brazing** (*feasibility study on-going*)



Copper part inserted into Steel flange

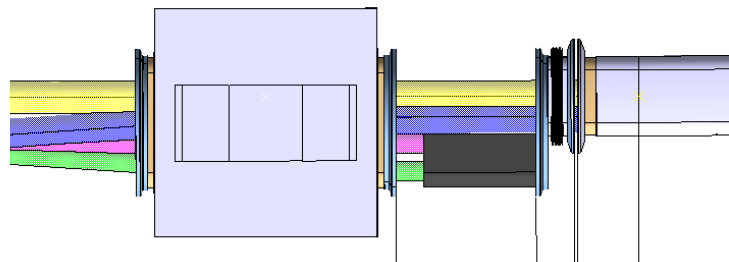


- **Shrinking**



For both solution:
- Metallic part inserted into Steel flange

Support shorter dipole



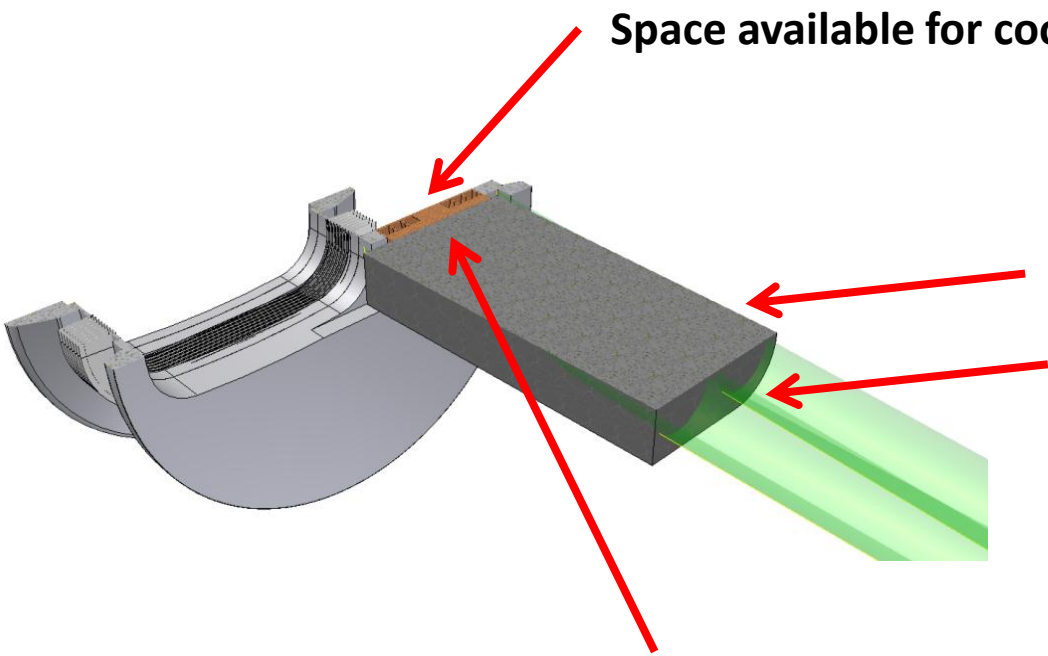
Need to be implemented within the area:

- *beam instrumentation*
- *dump support*
- *active cooling system (needed?)*

- **No brazing** between ceramic part and metallic one
- Possible to develop a **dedicated** dump **support**:
 - much easier,
 - BUT need to be defined.

Summary

Actual configuration:



Space available for cooling system: *sufficient?*

Complex dump shape: *feasible in SiC?*

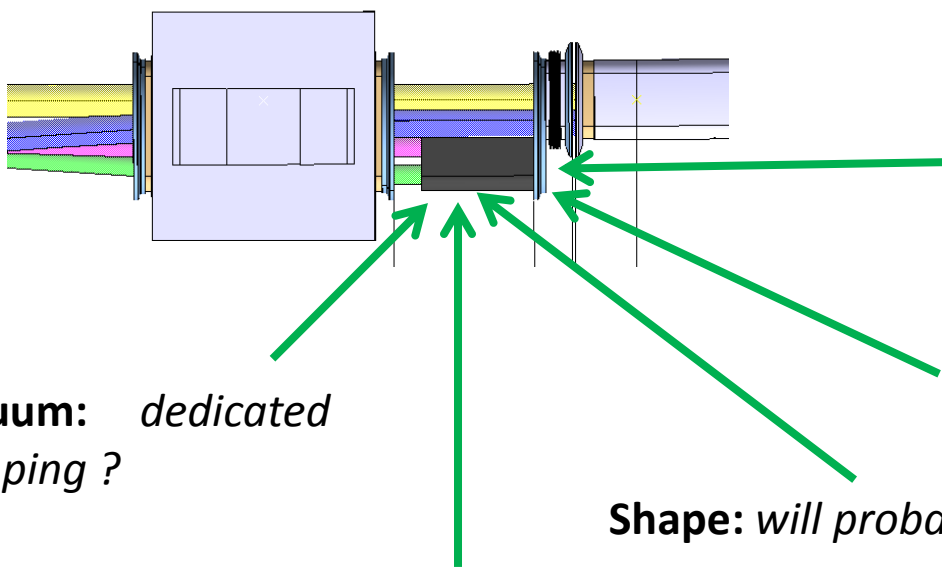
Beam instrumentation to implement: *easy to attach to SiC?*

Brazing between SiC and metallic part: *feasible?*

This solution seems to be feasible but need some R&D and partnership with external companies.

Summary

Shorter dipole configuration:



Vacuum: *dedicated pumping ?*

Cooling system: *mandatory? (max. Temp on dump with radiation only: about 350 °C).*

Support system: *still to be defined but easier.*

Shape: *will probably be simpler.*

Material: *can be modified (metallic, denser material allowed ?).*



Need to start the study from the beginning (Fluka analyses included).



Conclusions

	DUMP IN	DUMP OUT
Material restriction	YES	NO
Electrical charge	=	
Support system	SOME ISSUES	EASIER
Thermo-mechanical behavior	=	
Active cooling system	YES	NO (?)
Vacuum	SOME ISSUES	EASIER
Activation	=	
Need of dedicated shielding	NO	YES
Maintenance	Complicated (?)	Easier (?)
Price	More expensive	Less expensive
Solution development status	ADVANCED	∅
Need of R&D + material test	YES	NO (?)



Thank You



Loading cases

Table 1 - main machine parameters for H⁰/H⁻ beam dump definition.

EDMS 963395

Ion species		H ⁻ /H ⁰
Beam energy (kinetic)	MeV	160
Max. repetition rate	Hz	1.11
Max. Beam pulse length (useful beam)	μs	400
Injection turns		4 x 100
Beam head/tail length	μs	<60/20
Peak LINAC current	mA	40
RFQ peak current	mA	70
Average LINAC current	mA	0.018
Max. beam power	kW	2.8
Max Nbr. of particles per beam pulse		1.0 x 10 ¹⁴

Operation:

Three loading case (following stripping efficiency):

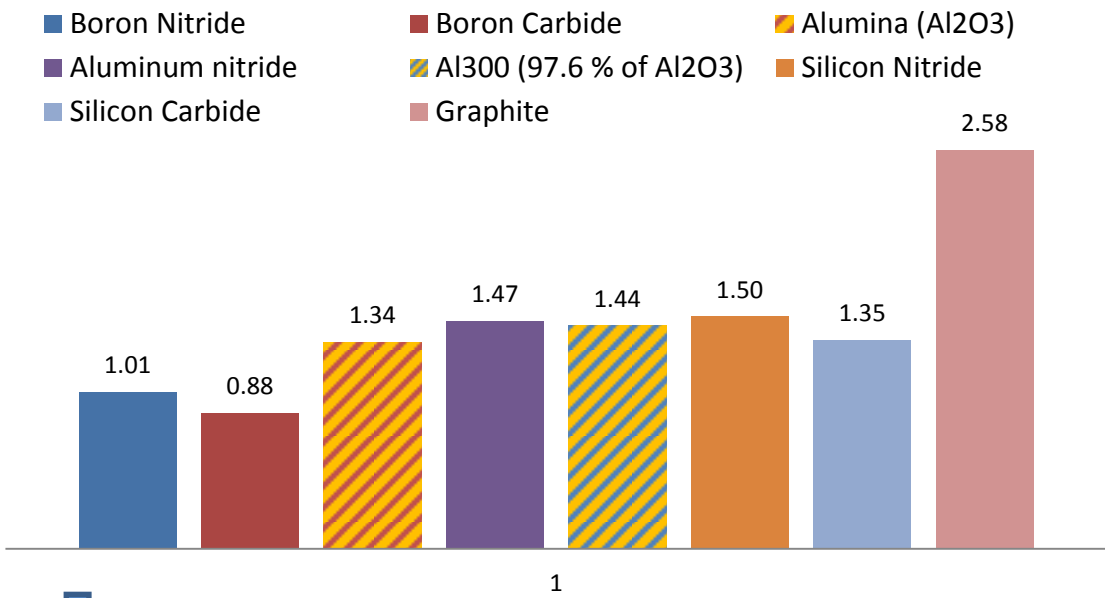
- Case 1: efficiency = 98% (foil **operational**) -- > Steady-state, 2% all H⁰, 0.8mA
- Case 2: efficiency = 90% (foil **degraded**) -- > Steady-state, 10% all H⁰, 4mA, **8h max**
- Case 3: efficiency = 0% (foil **accident**) -- > Transient 1/4 Linac4 pulse, 40mA, 100% H⁻ (**interlock after 1 pulse**)

4/4 Linac4 Beam loading case (foil accident + distributor failure)

-- > **not considered**

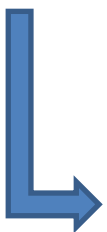
Material choice

FOMS summary: to be minimized



ON/OFF properties

	<i>Discharged entirely at the end of the pulse (50 V)</i>	<i>Weld ability</i>
<i>Boron Nitride</i>	✗	✗
<i>Boron Carbide</i>	✗	✗
<i>Alumina</i>	✗	✓
<i>Aluminum nitride</i>	✗	✗
<i>Al300</i>	✗	✓
<i>Silicon Nitride</i>	✗	✗
<i>Silicon Carbide</i>	✓	✓
<i>Graphite</i>	✓	✗



Due to their electrical behavior, Silicon Carbide (SiC) and Graphite are the only suitable material. However, Graphite will induce problems on a vacuum point of view and for the support. **SiC** has thus been chosen for the dump core.

Thermal consideration

be taken that this will be compatible with the maximum temperature allowed for the magnet and the ceramic vacuum chamber.

↳ Do we need an **active cooling**?

In a first time, **no active cooling** is considered: the only heat exchange is made by thermal radiation → $P(W) = \varepsilon \cdot \sigma \cdot S \cdot (T_{dump}^4 - T_{env}^4)$

↳ To this temperature, the peak temperature rise due to the instantaneous impact of the beam has to be added (approximation)

$$-\frac{dE}{dx} \propto \frac{Z\rho}{A} \quad \longrightarrow \quad \Delta T^* \propto \frac{Z}{Ac_p}$$

Bethe-Block *Adiabatic non-diffusive model*

The maximum temperature in the dump core must stay under the working temperature of its material:

$$FOM_1 = \frac{T^*}{T_c} \leq 1$$

Structural consideration

The dump must withstand continuous load of 2 to 10% of the beam or 1 full pulse

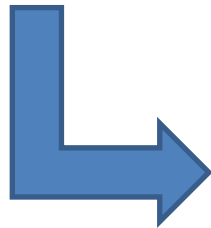
↳ Structural behavior of the different material must be taken into account.

$$\sigma_{th} = E \cdot \alpha \cdot \Delta T \quad \text{and} \quad \frac{\sigma_{th}}{R_c} \leq 1$$

Thermal stress

With R_c = limit in compression

NB: *On the peak position, stresses only due to compression.*



$$FOM_2 = \frac{Z \cdot \alpha \cdot E}{A \cdot C_p \cdot R_c} \leq 1$$

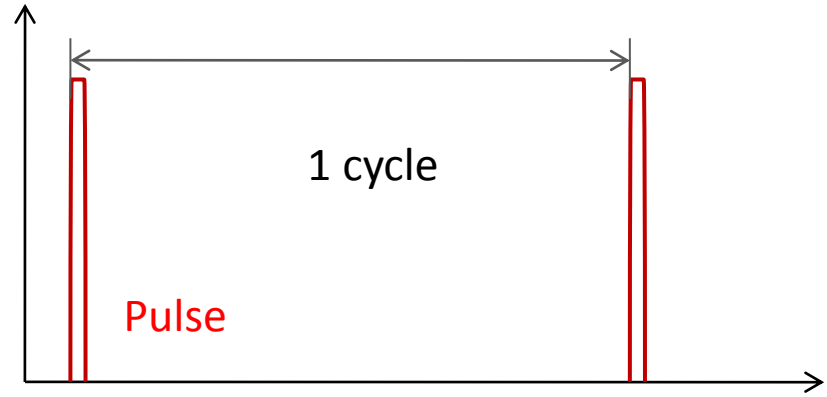
Electrical behavior (1)

A completely insulating dump material will risk electrical charging

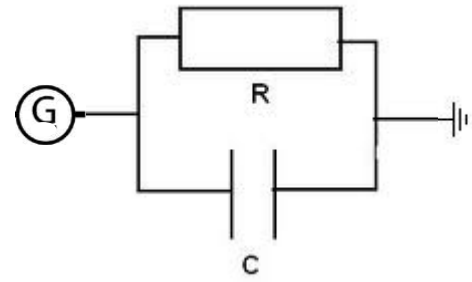
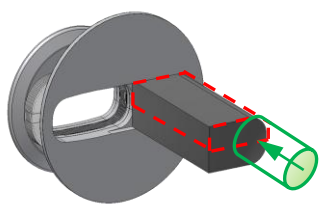
How?

Conservative approximated model to define the electrical behavior of material

→ the full charge of the beam is deposited in the material during the charge.



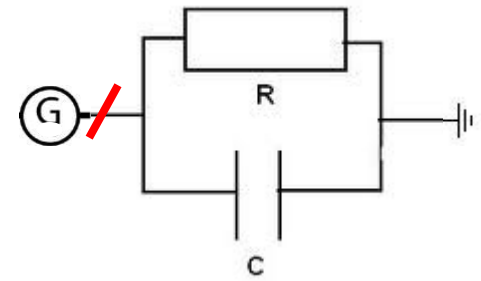
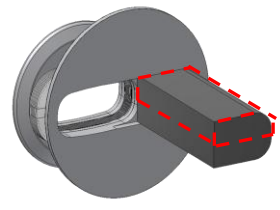
Beam → Charge: parallel RC model



$$V(t) = I_b(t) \cdot \left(\frac{C}{t} + \frac{1}{R} \right)^{-1}$$

$t = \text{pulse length}$

NO Beam → Discharge: series RC model



$$V(t) = V_C(t) = V_{initial} \cdot \exp\left(-\frac{t}{RC}\right)$$

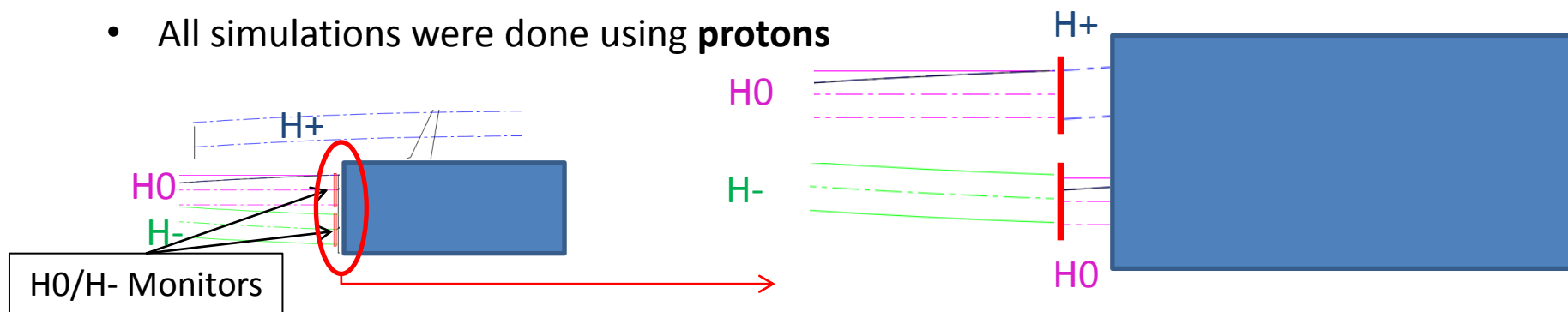
$t = \text{cycle length}$

Electrical behavior (2)

In reality, some charges escape from the dump surfaces while the “charging” phase
 → Fluka simulation were done to assess the % of escaping charges.

Assumptions:

- All simulations were done using **protons**



- Surfaces considered for particle flux evaluation: **all**
- Charges: positive and negative. The total one is the **difference between positive and negative** (in absolute value) charges.

Electrical behavior (3)

3 studied cases results	Graphite	Al300	SiC	
Total Charge, full beam (V)	1.07e-7	22500	1.98	← End of pulse
Total charges escaping (C/p+)	8.38e-21	4.49e-22	1.27e-21	
% escaping (Fluka)	5.23	0.28	0.79	
Charge accumulated (Fluka) (V)	1.01e-7	22400	1.96	← End of pulse
Charge after Discharge (V)	0	22200	0	← End of full cycle

The maximum charged allowed in the dump core was set to **50 V** (suggestion from Michael Plum, Oak Ridge National Laboratory).

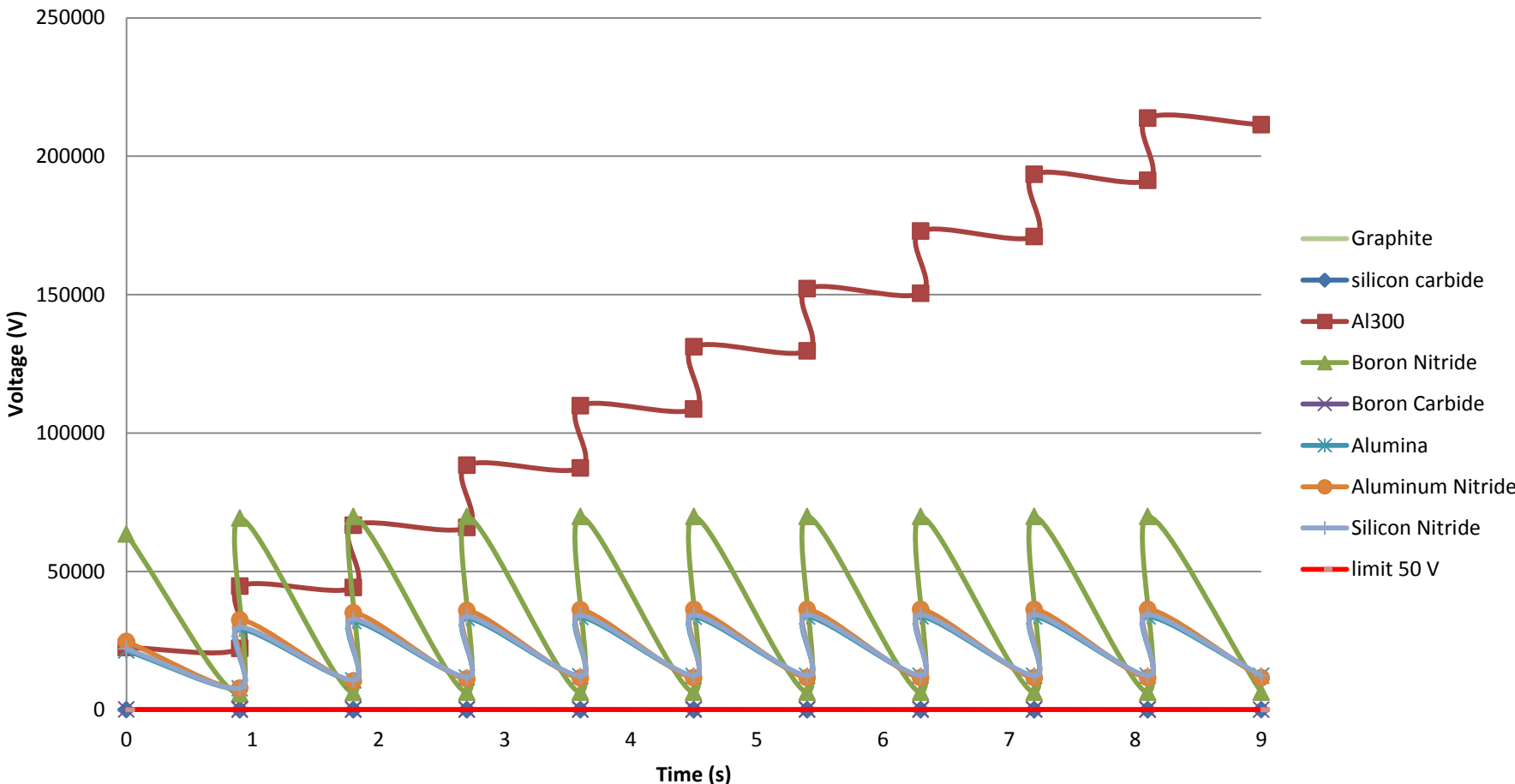


ON/OFF property

Results for the loading case 2: 10 % of the beam, H0 beam, only 1 cycle considered.

Electrical behavior (4)

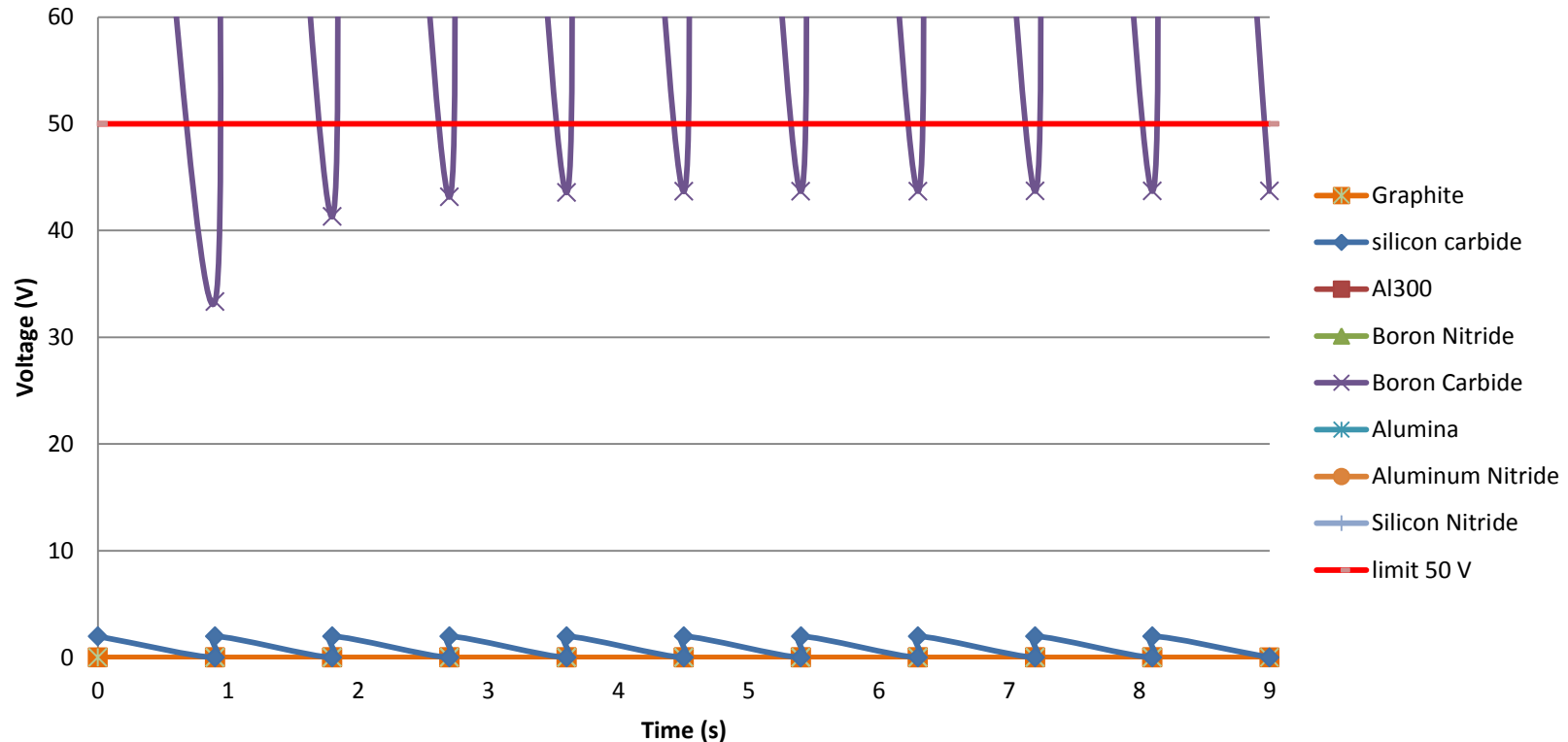
Accumulated charged during 9 seconds



Electrical behavior (5)

ZOOM

Accumulated charged during 9 seconds



Only Silicon Carbide and Graphite fulfill the electrical requirements (limit at 50 V)



Electrical properties

	<i>Resistance (ohm)</i>	<i>dielec. Cte</i>	<i>Capacitance</i>	<i>RC</i>	<i>-t/τ</i>	<i>exp(-t/τ)</i>	
Boron Nitride	2.98E+11	4.24	1.26E-12	3.75E-01	-2.40E+00	0.090955817	5.73E+03
Boron Carbide	1.12E+09	6.93	5.49E-10	6.14E-01	-1.47E+00	0.230663317	3.33E+01
Aluminium							0
Graphite	1.33E-04	13.50	3.58E-12	4.78E-16	-1.88E+15	0	0
Alumina	2.39E+11	10.10	3.74E-12	8.94E-01	-1.01E+00	0.365523222	7752.422409
Aluminum nitride	2.44E+11	8.94	3.25E-12	7.92E-01	-1.14E+00	0.320775713	7843.785291
Al300 (97.6 % of Al2O3)	2.24E+13	9.00	3.56E-12	7.97E+01	-1.13E-02	0.988769211	22173.83272
Silicon Nitride	2.43E+11	9.99	3.64E-12	8.85E-01	-1.02E+00	0.361494942	7887.387339
Silicon Carbide	2.47E+03	7.94	2.84E-12	7.03E-09	-1.28E+08	0	0

Vacuum and activation

 Low outgassing rate required.

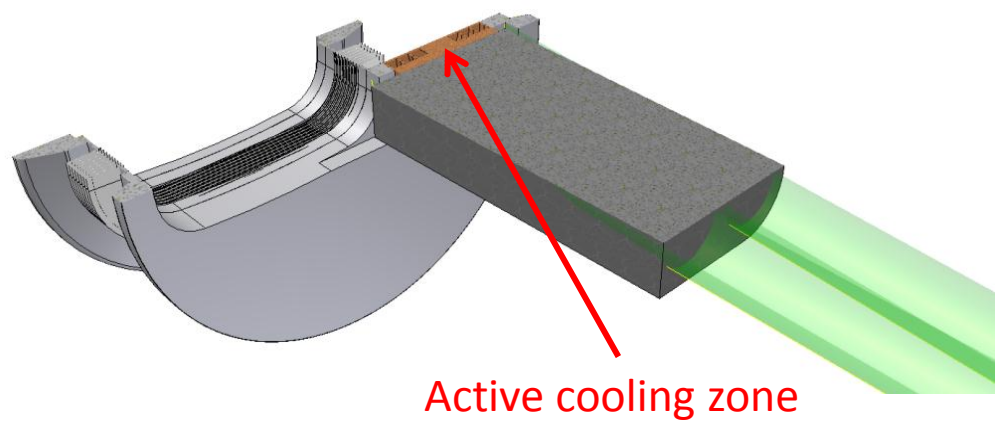
$$FOM_3 = \text{porosity}$$

The residual dose should be minimised in the design, by the choice of materials and geometry.

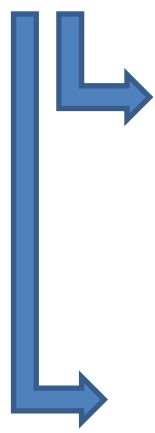
 Activation considered as approximately proportional to the atomic number of the material Z.

$$FOM_4 = Z$$

Studied solution



→ Dump in Silicon Carbide



Silicon Carbide brazed on metallic insert:

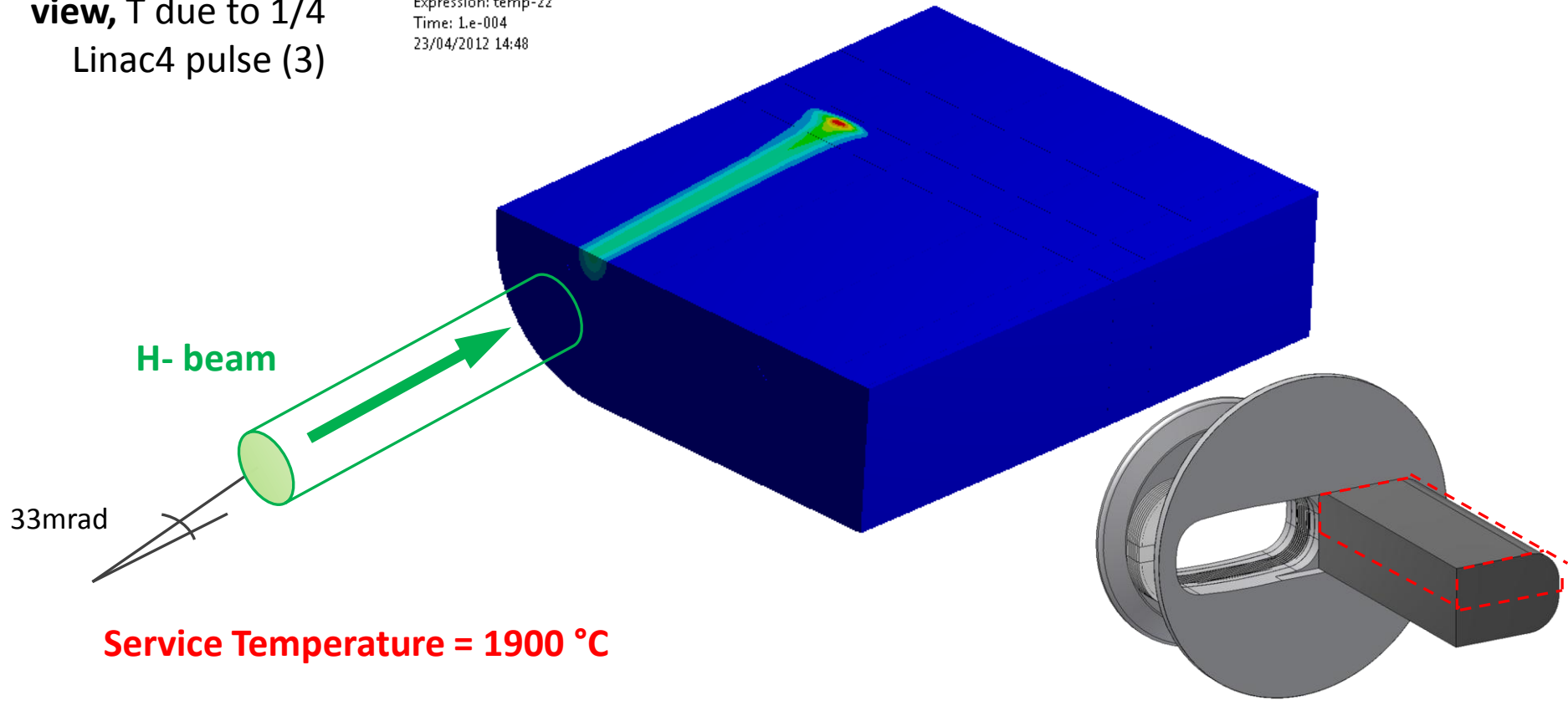
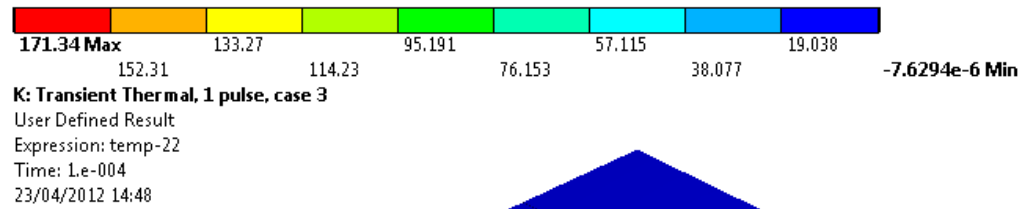
- Molybdene
- Tungsten
- Kovar (Ni/Fe/Cu)

Flow considered for active cooling: $0.5 \text{ m}^3/\text{h}$ (highly pessimistic)

Instantaneous ΔT – SiC

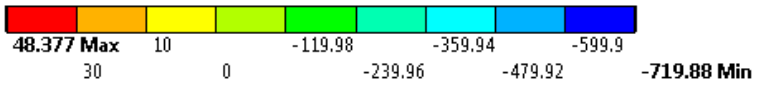
Case 3

Half dump **BOTTOM**
view, T due to 1/4
Linac4 pulse (3)



Instantaneous eq. Stassi – SiC

Case 3

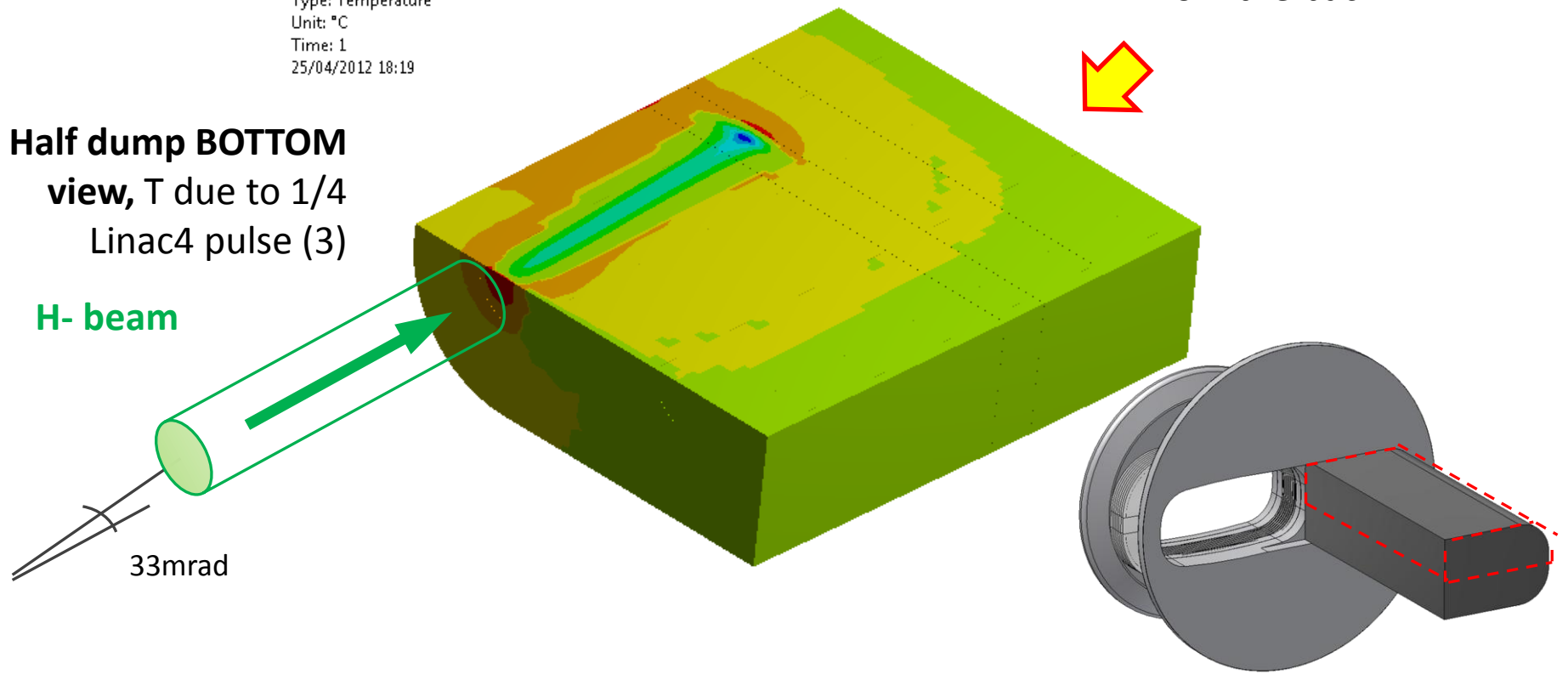


C: Transient Thermal
Temperature
Type: Temperature
Unit: °C
Time: 1
25/04/2012 18:19

Fixed support
from the back

Half dump BOTTOM
view, T due to 1/4
Linac4 pulse (3)

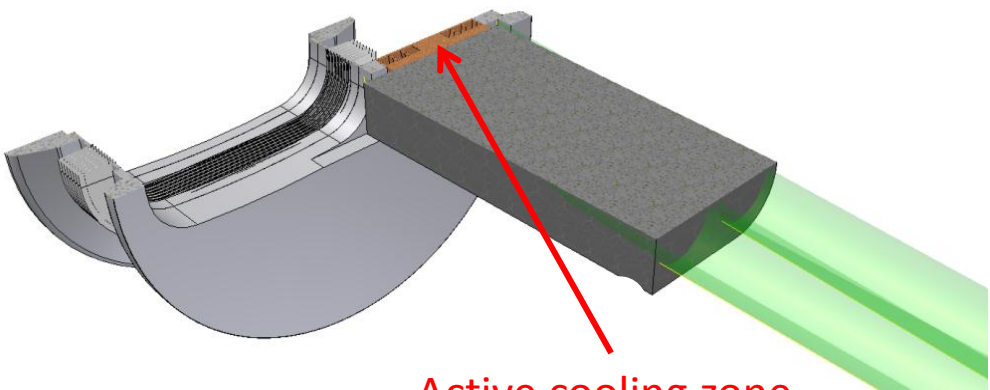
H- beam



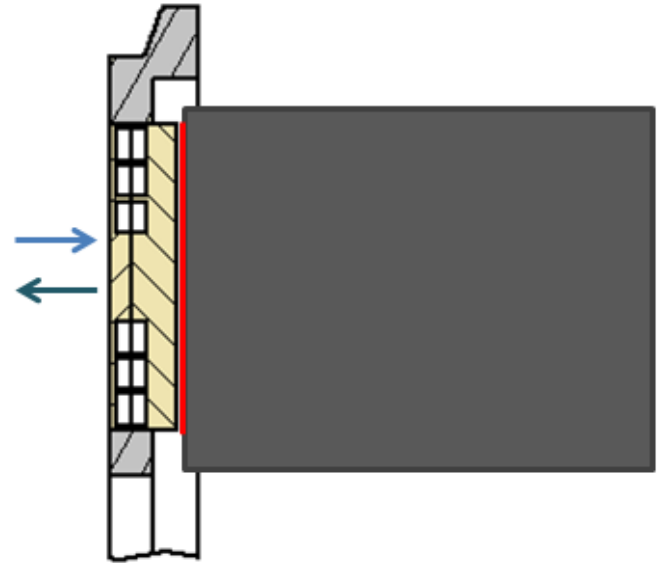
Static Limit in tension: 390 Mpa
Static Limit in compression: 3900 Mpa

Safety factor_{tension}: 7.9
Safety factor_{compression}: 5.1

Steady operation – SiC (4)

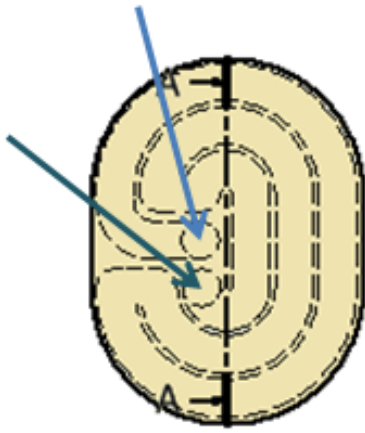


Active cooling zone

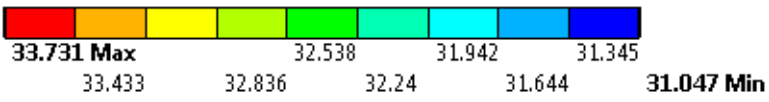


Entrance for water cooling

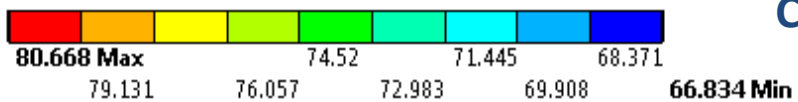
Exit for water cooling



Steady operation – SiC (5)

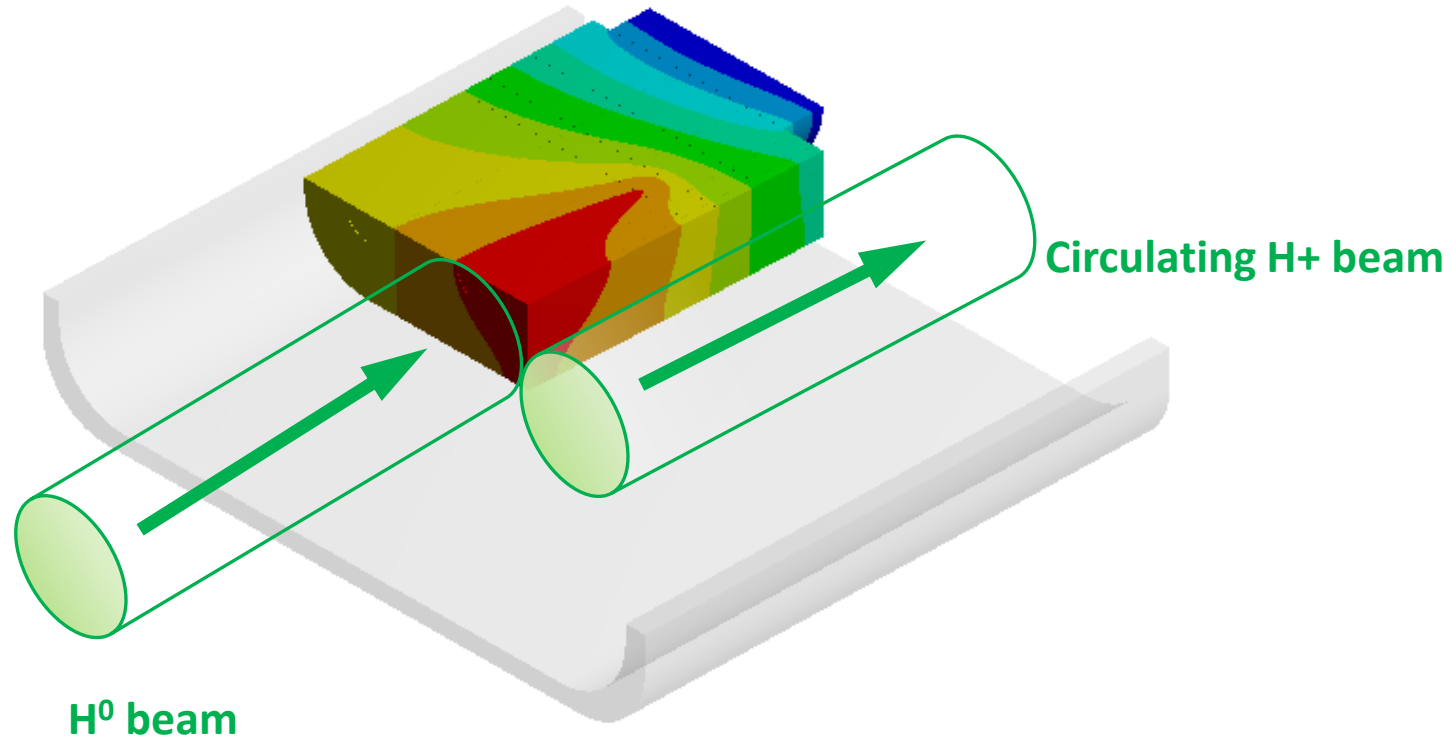


Case 1



Case 2

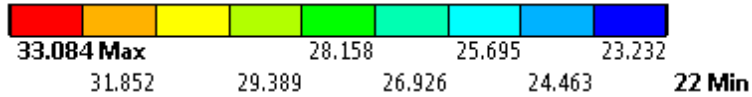
Half dump BOTTOM view, T
due to steady-state operation



Active cooling: heat exchange with radiation and convection

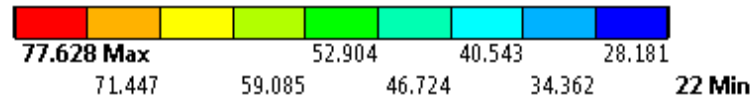


Steady operation – SiC (6)

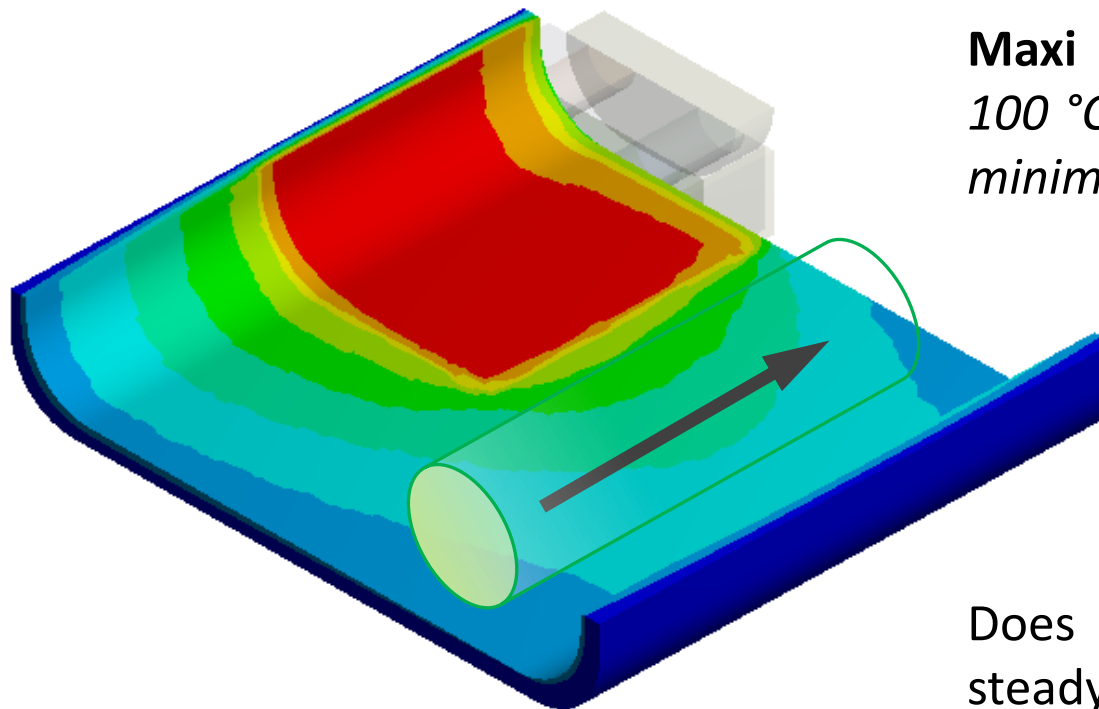


Case 1

Half dump BOTTOM view, T
due to steady-state operation



Case 2



Maxi temperature on chamber:
100 °C and gradient of T must be minimized.

Does the chamber reach the steady state in 8 hours for the case 2? → TBC



Dump space and layout: actual design

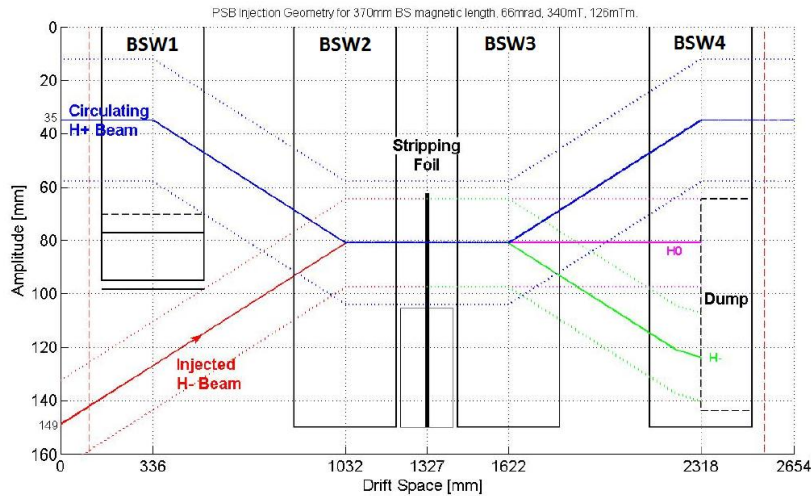


Figure 3: Possible configuration for the PSB injection region, showing injected and circulating (first turn) beam envelopes of $\pm 4\sigma$ for $\pm 0.4\%$ $\delta p/p$ variation (BSW positions and length are subject to change).

EDMS 963395

No differentiation between H^0 and H^- loads

H- impact angle: assumed $\sim 33\text{mrad}$ (J. Borburgh)

EDMS 1069240, 44

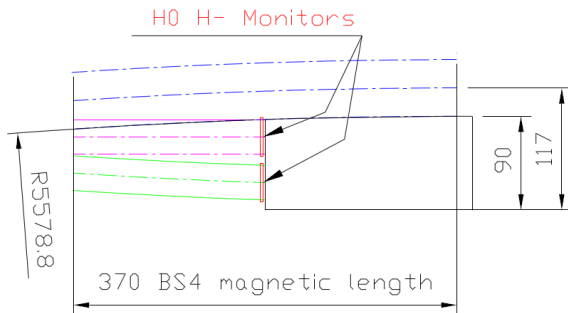


Figure 5: Top view of the H^0/H^- beam dump and H^0/H^- monitor.

